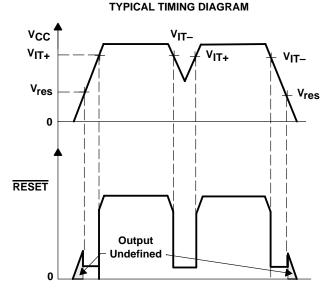
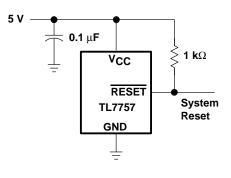
#### available features

- Power-On Reset Generator
- Automatic Reset Generation After Voltage Drop
- Low Standby Current . . . 20 μA
- Reset Output Defined When V<sub>CC</sub> Exceeds 1 V



- Complementary Reset Output
- Precision Threshold Voltage 4.55 V ±120 mV
- High Output Sink Capability . . . 20 mA
- Comparator Hysteresis Prevents Erratic Resets

#### TYPICAL APPLICATION DIAGRAM



#### description

The TL7757 is a monolithic supply voltage supervisor designed for use in microcomputer and microprocessor systems. The supervisor monitors the supply voltage for undervoltage conditions. During power up, when the supply voltage,  $V_{CC}$ , attains a value approaching 1 V, the RESET output becomes active (low) to prevent undefined operation. If at any time, the supply voltage drops below threshold voltage level ( $V_{IT-}$ ), the RESET output goes to the active (low) level until the supply undervoltage fault condition is eliminated.

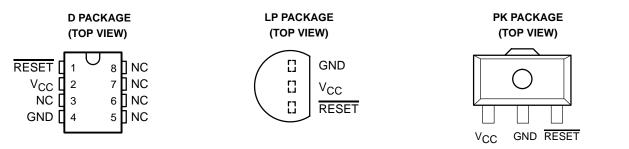
The C-suffix device is characterized for operation from 0°C to 70°C. The I-suffix device is characterized for operation from -40°C to 85°C. The M-suffix device is characterized for operation from -55°C to 125°C.

	AVAILABLE OPTIONS								
	PACK	AGED DEVICES		CHIP FORM					
TA	SMALL OUTLINE (D)	TO-226AA (LP)	SOT-89 (PK)	спіг гокмі (Y)					
0°C to 70°C	TL7757CD	TL7757CLP	TL7757CPK						
-40°C to 85°C	TL7757ID	TL7757ILP	TL7757IPK	TL7757Y					
-55°C to 125°C	TL7757MD	TL7757MLP	_						

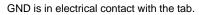
## AVAILABLE OPTIONS

D and LP packages are available taped and reeled. Add R suffix to device type (e.g., TL7757CDR). Chips are tested at  $25^{\circ}$ C.



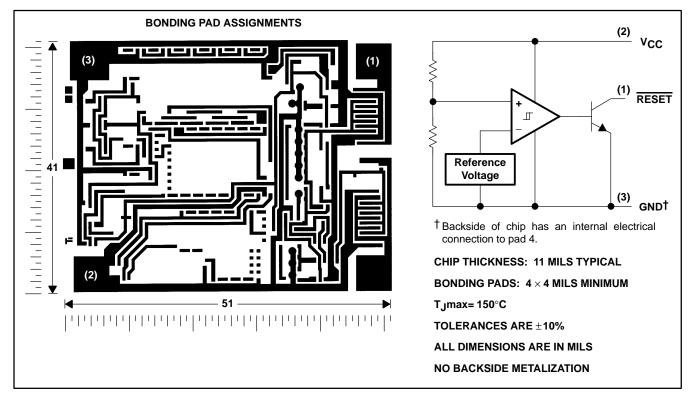


NC-No internal connection



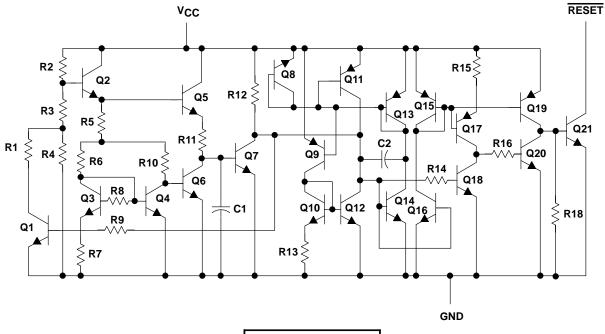
## **TL7757Y** chip information

This chip, when properly assembled, displays characteristics similar to the TL7757C. Thermal compression or ultrasonic bonding may be used on the doped aluminum bonding pads. The chips may be mounted with conductive epoxy or a gold-silicon preform.





## equivalent schematic



ACTUAL I COMPONEN					
Transistors 27					
Resistors	20				
Capacitors	2				



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## absolute maximum ratings over operating free-air temperature (unless otherwise noted)<sup>†</sup>

Supply voltage range, V <sub>CC</sub> (see Note 1)	0.3 V to 20 V
Output current, I <sub>O</sub>	
Operating free-air temperature range, T <sub>A</sub> : C-suffix	0°C to 70°C
I-suffix	–40°C to 85°C
M-suffix	–55°C to 125°C
Continuous total power dissipation	See Dissipation Rating Tables
Storage temperature range, T <sub>stg</sub>	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds .	260°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to network terminal ground.

#### **DISSIPATION RATING TABLE 1 – FREE-AIR TEMPERATURE**

PACKAGE	T <sub>A</sub> ≤ 25°C POWER RATING	DERATING FACTOR	DERATE ABOVE	T <sub>A</sub> = 70°C	T <sub>A</sub> =ੴ⊃°C	T <sub>A</sub> = 125°C
D	725 mW	5.8 mW/°C	$T_A = 25^{\circ}C$	464 mW	377 mW	145 mW
LP	775 mW	6.2 mW/°C	$T_A = 25^{\circ}C$	496 mW	403 mW	155 mW
PK	500 mW	4.0 mW/°C	$T_A = 25^{\circ}C$	320 mW	260 mW	—

#### **DISSIPATION RATING TABLE 2 – CASE TEMPERATURE**

PACKAGE	T <sub>A</sub> ≤ 25°C POWER RATING	DERATING FACTOR	DERATE ABOVE	T <sub>A</sub> = 70°C	T <sub>A</sub> =ੴ5°C
PK	3125 mW	25 mW/°C	T <sub>C</sub> =110°C	2000 mW	1625 mW

#### recommended operating conditions

	C-SU	FFIX	I-SUF	FIX	M-SU	FFIX	UNIT
	MIN MAX MIN MAX MIN		MAX				
Supply voltage, V <sub>CC</sub>	1	7	1	7	1	7	V
High-level output voltage, V <sub>OH</sub>		15		15		15	V
Low-level output current, IOL		20		20		20	mA
Operating free-air temperature, T <sub>A</sub>	0	70	-40	85	-55	125	°C



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	DADAMETED	TEST CONDITIONS	<b>-</b> +	Т	L7757C		
	PARAMETER	TEST CONDITIONS	T <sub>A</sub> †	MIN	TYP	MAX 4.67 4.7 60 70 0.8 0.8 0.8 1 1 1 1 2000 2000	UNIT
V	Negative going input threshold voltage at Ver		25°C	4.43	4.55	4.67	v
VIT-	Negative-going input threshold voltage at $V_{CC}$		Full range	4.4		4.7	v
v. +	Hysteresis at V <sub>CC</sub>		25°C	40	50	60	mV
v <sub>hys</sub> ‡			Full range	30		70	IIIV
Vei	Low-level output voltage	a  = 20  m  (a - 4.2)/	25°C		0.4	0.8	v
VOL	Low-level output voltage	loi = 20  mA $Voc = 4.3  V$	Full range			0.8	v
lou	High-level output current	V <sub>CC</sub> = 7 V, V <sub>OH</sub> = 15 V,	25°C			1	μA
ЮН	ngn-level output current	See Figure 1	Full range			1	μA
v 8	Power-up reset voltage	$R_{L} = 2.2 \text{ k}\Omega$ ,	25°C		0.8	1	V
v <sub>res</sub> §	Power-up reservoitage	$V_{CC}^{-}$ slew rate $\leq 5 V/\mu s$	Full range			1.2	v
		$\lambda = 42 \lambda$	25°C		1400	2000	
ICC	Supply current	$V_{CC} = 4.3 V$	Full range			2000	μA
		V <sub>CC</sub> = 5.5 V	Full range			40	

### electrical characteristics at specified free-air temperature

<sup>†</sup> Full range is 0°C to 70°C. <sup>‡</sup> This is the difference between positive-going input threshold voltage, V<sub>IT+</sub>, and negative-going input threshold voltage, V<sub>IT-</sub>. § This is the lowest voltage at which RESET becomes active.

## switching characteristics at $T_{A}$ = 25°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	<b>.</b> +	TL7757C				
	PARAMETER	TEST CONDITIONS	τ <sub>A</sub> †	MIN	TYP	MAX	UNIT	
touu	Propagation delay time, low-to-high-level output	$V_{CC}$ slew rate $\leq 5 V/\mu s$ ,	25°C		3.4	5	μs	
<sup>t</sup> PLH		See Figures 2 and 3	Full range			5	μs	
	Propagation delay time, high-to-low-level output	See Figuree 2 and 2	25°C		2	5		
<sup>t</sup> PHL	Propagation delay time, high-to-low-level output	See Figures 2 and 5	Full range			5	μs	
	Rise time	V <sub>CC</sub> slew rate $\leq$ 5 V/µs,	25°C		0.4	1		
t <sub>r</sub>	Rise une	See Figures 2 and 3	See Figures 2 and 3 Full	Full range			1	μs
<b>.</b>	Fall time	See Figuree 2 and 2	25°C		0.05	1		
tf		See Figures 2 and 3	Full range			1	μs	
• • • •	Minimum pulse duration at Vala for output response		25°C			5		
<sup>t</sup> w(min)	Minimum pulse duration at $V_{CC}$ for output response		Full range			5	μs	

<sup>†</sup> Full range is 0°C to 70°C.



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## electrical characteristics at specified free-air temperature

	PARAMETER	TEST CONDITIONS	<b>.</b> .+	٦	FL7757I		
	PARAMETER	TEST CONDITIONS	Τ <sub>Α</sub> †	MIN	TYP	YP MAX   1.55 4.67   50 60   70 0.4   0.4 0.8   1 1   0.8 1   1.2 2000   2100 2100	UNIT
V	Negative-going input threshold voltage at $V_{CC}$		25°C	4.43	4.55	4.67	V
VIT-	Negative-going input theshold voltage at VCC		Full range	4.4		4.7	v
V. +			25°C	40	50	60	mV
V <sub>hys</sub> ‡	Hysteresis at V <sub>CC</sub>		Full range	30		70	IIIV
Val		a  = 20  m $ a  = 4.2  V$	25°C		0.4	0.8	V
VOL	Low-level output voltage	$I_{OL} = 20 \text{ mA},  V_{CC} = 4.3 \text{ V}$	Full range			0.8	v
1	High level output ourroat	V <sub>CC</sub> = 7 V, V <sub>OH</sub> = 15 V,	25°C			1	
ЮН	High-level output current	See Figure 1	Full range			1	μA
V 8	Power up react voltage	$R_{L} = 2.2 \text{ k}\Omega,$	25°C		0.8	1	V
v <sub>res</sub> §	Power-up reset voltage	$V_{CC}^{-}$ slew rate $\leq 5 V/\mu s$	Full range			1.2	v
		1/22 - 4.2 1/2	25°C		1400	2000	
ICC	Supply current	V <sub>CC</sub> = 4.3 V	Full range			2100	μΑ
		V <sub>CC</sub> = 5.5 V	Full range			40	

<sup>†</sup> Full range is –40°C to 85°C.

<sup>‡</sup>This is the difference between positive-going input threshold voltage,  $V_{IT+}$ , and negative-going input threshold voltage,  $V_{IT-}$ . § This is the lowest voltage at which RESET becomes active.

## switching characteristics at $T_{A}$ = 25°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	<b>.</b> .+	٦	L7757I		
	PARAMEIER	TEST CONDITIONS	Τ <sub>Α</sub> †	MIN	TYP	MAX	UNIT
t	Propagation delay time, low-to-high-level output	$V_{CC}$ slew rate $\leq 5 V/\mu s$ ,	25°C		3.4	5	
<sup>t</sup> PLH	Propagation delay time, low-to-high-level output	See Figures 2 and 3	Full range			5	μs
tout	Propagation delay time, high-to-low-level output	See Figures 2 and 3	25°C		2	5	
<sup>t</sup> PHL	Propagation delay time, high-to-low-level output	See Figures 2 and 5	Full range			5	μs
	Rise time	V <sub>CC</sub> slew rate $\leq$ 5 V/µs,	25°C		0.4	1	
t <sub>r</sub>	Rise time	See Figures 2 and 3	Full range			1	μs
<b>.</b>	Fall time	See Figures 2 and 2	25°C		0.05	1	
t <sub>f</sub>	Fairume	See Figures 2 and 3	Full range			1	μs
• • • • •			25°C			5	
<sup>t</sup> w(min)	Minimum pulse duration at $V_{CC}$ for output response		Full range			5	μs

<sup>†</sup>Full range is –40°C to 85°C.



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	DADAMETER	TEST CONDITIONS	<b>T</b> . †	Т	L7757M			
	PARAMETER	TEST CONDITIONS	T <sub>A</sub> †	MIN	TYP	MAX   4.67   4.7   60   70   0.8   0.8   1   1   1.2   2000   2500	UNIT	
V	Negative-going input threshold voltage at $V_{CC}$		25°C	4.43	4.55	4.67	v	
VIT-			Full range	4.35		4.7	v	
v. t			25°C	40	50	60	mV	
v <sub>hys</sub> ‡	Hysteresis at V <sub>CC</sub>		Full range	30		70	mv	
Va		10, 20 m/ 1/00, 42 1/	25°C		0.4	0.8	v	
VOL	Low-level output voltage	$I_{OI} = 20 \text{ mA}$ . $V_{CC} = 4.3 \text{ V}$	OL = 20  MA,  VCC = 4.3  V	Full range			0.8	v
lau	High-level output current	V <sub>CC</sub> = 7 V, V <sub>OH</sub> = 15 V,	25°C			1		
ЮН	High-level output current	See Figure 1	Full range			1	μA	
V 8		$R_{\rm I} = 2.2  \rm k\Omega$ ,	25°C		0.8	1	V	
v <sub>res</sub> §	Power-up reset voltage	$V_{CC}^{-}$ slew rate $\leq 5 V/\mu s$	Full range			1.2	v	
			25°C		1400	2000		
ICC	Supply current	V <sub>CC</sub> = 4.3 V	Full range			2500	μA	
		V <sub>CC</sub> = 5.5 V	Full range			40		

### electrical characteristics at specified free-air temperature

<sup>†</sup>Full range is –55°C to 125°C.

<sup>‡</sup> This is the difference between positive-going input threshold voltage,  $V_{IT+}$ , and negative-going input threshold voltage,  $V_{IT-}$ . § This is the lowest voltage at which RESET becomes active.

## switching characteristics at $T_A = 25^{\circ}C$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	<b>.</b> +	Т	L7757M		
	PARAMETER	TEST CONDITIONS	ΤA <sup>†</sup>	MIN	TYP	MAX	UNIT
tour	Propagation delay time, low-to-high-level output	$V_{CC}$ slew rate $\leq 5 V/\mu s$ ,	25°C		3.4	5*	μs
<sup>t</sup> PLH	Propagation delay time, low-to-nigh-level output	See Figures 2 and 3	Full range			5*	μs
	Propagation delay time, high-to-low-level output	See Figures 2 and 3	25°C		2	5*	
<sup>t</sup> PHL	Propagation delay time, high-to-tow-level output	See Figures 2 and 5	Full range			5*	μs
	Rise time	V <sub>CC</sub> slew rate $\leq$ 5 V/µs,	25°C		0.4	1*	
tr	Rise time	See Figures 2 and 3	Full range			1*	μs
	Fall time	See Figures 2 and 3	25°C		0.05	1*	
t <sub>f</sub>	Fail unie	See Figures 2 and 5	Full range			1	μs
• • • • •			25°C			5*	
<sup>t</sup> w(min)	Minimum pulse duration at $V_{CC}$ for output response		Full range			5*	μs

\*On products compliant to MIL-STD-883, Class B, this parameter is not production tested.

<sup>†</sup> Full range is –55°C to 125°C.



## electrical characteristics at $T_A$ = 25°C

PARAMETER		TEST CONDITIONS	TL7757Y				
		TEST CONDITIONS	MIN	TYP	MAX	UNIT	
$V_{IT-}$	Negative-going input threshold voltage at $V_{CC}$			4.55		V	
V <sub>hys</sub> †	Hysteresis at $V_{CC}$			50		mV	
VOL	Low-level output voltage	$I_{OL} = 20 \text{ mA},  V_{CC} = 4.3 \text{ V}$		0.4		V	
ЮН	High-level output current	$V_{CC} = 7 V$ , $V_{OH} = 15 V$ , See Figure 1				μA	
V <sub>res</sub> ‡	Power-up reset voltage	$R_L = 2.2 \text{ k}\Omega$ , $V_{CC}$ slew rate $\leq 5 \text{ V/}\mu\text{s}$		0.8		V	
ICC	Supply current	$V_{CC} = 4.3 V$		1400		μA	
		V <sub>CC</sub> = 5.5 V					

<sup>†</sup> This is the difference between positive-going input threshold voltage, V<sub>IT+</sub>, and negative-going input threshold voltage, V<sub>IT-</sub>. <sup>‡</sup> This is the lowest voltage at which RESET becomes active.

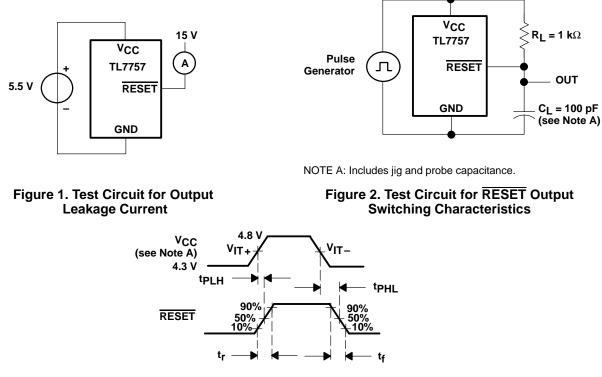
## switching characteristics at $T_{A}$ = 25°C

PARAMETER		TEST CONDITIONS	TL7757Y			
		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<sup>t</sup> PLH	Propagation delay time, low-to-high-level output	$V_{CC}$ slew rate $\leq$ 5 V/µs, See Figures 2 and 3		3.4		μs
<sup>t</sup> PHL	Propagation delay time, high-to-low-level output	See Figures 2 and 3		2		μs
t <sub>r</sub>	Rise time	$V_{CC}$ slew rate $\leq$ 5 V/µs, See Figures 2 and 3		0.4		μs
t <sub>f</sub>	Fall time	See Figures 2 and 3		0.05		μs



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## PARAMETER MEASUREMENT INFORMATION



NOTE A: V<sub>CC</sub> slew rate  $\leq$  5 µs

Figure 3. Switching Diagram

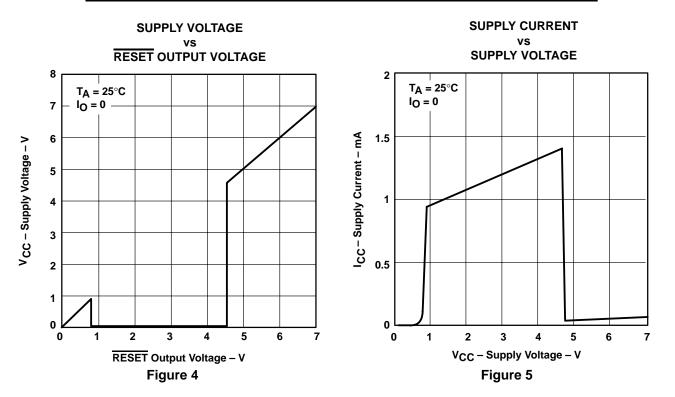


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## **TYPICAL CHARACTERISTICS<sup>†</sup>**

### **Table of Graphs**

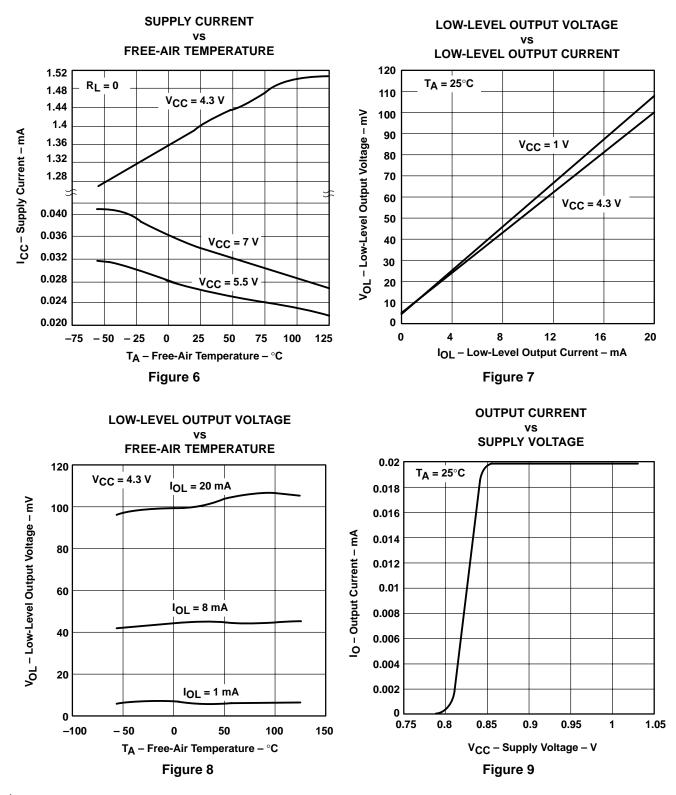
			FIGURE
VCC	Supply voltage	vs RESET output voltage	4
Icc	Supply current	vs Supply voltage	5
	Supply current	vs Free-air temperature	6
Vai		vs Low-level output current	7
VOL	Low-level output voltage	vs Free-air temperature	8
IOL	Output current	vs Supply voltage	9
VIT-	Input threshold voltage (negative-going V <sub>CC</sub> )	vs Free-air temperature	10
Vres	Power-up reset voltage	vs Free-air temperature	11
V <sub>res</sub>	Power-up reset voltage and supply voltage	vs Time	12
	Propagation delay time		13



<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



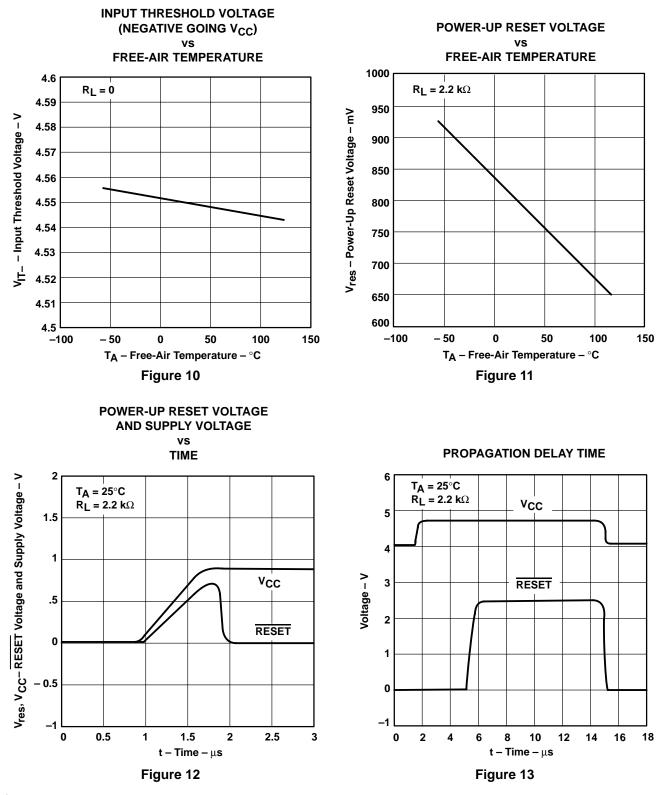
### **TYPICAL CHARACTERISTICS<sup>†</sup>**



<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



## **TYPICAL CHARACTERISTICS<sup>†</sup>**



<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



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